

# STTH60L04W

## Ultrafast high voltage rectifier

### Mian product characteristics

I <sub>F(AV)</sub>	60 A
V <sub>RRM</sub>	400 V
T <sub>j</sub> (max)	175° C
V <sub>F</sub> (typ)	0.83 V
t <sub>rr</sub> (max)	50 ns

### **Features and benefits**

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses

### Description

The STTH60L04W uses ST 400 V technology and is specially suited for use in switching power supplies, welding equipment, and industrial applications, as an output rectification diode.



### Order codes

Part number	Marking	
STTH60L04W	STTH60L04	

### Table 1. Absolute ratings (limiting values, per diode)

Symbol	Para	neter		Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage			400	V
I <sub>F(RMS)</sub>	RMS forward current			90	А
I <sub>F(AV)</sub>	Average forward current	$T_c = 90^\circ C \delta = 0.5$	Per diode	60	А
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoidal		600	А
T <sub>stg</sub>	Storage temperature range	·		-55 to + 175	°C
Тj	Maximum operating junction temperatu	ıre		175	°C

#### **Characteristics** 1

Symbol		Parameter	Value (max).	Unit
R <sub>th(j-c)</sub>	Junction to		0.70	°C/W
u (j=C)	case			

#### Table 3. Static electrical characteristics (per diode)

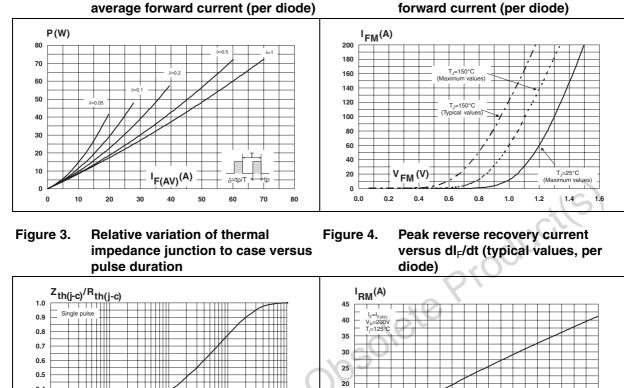
Symbol	Parameter	Test co	nditions	Min.	Тур	Max.	Unit
I <sub>B</sub> <sup>(1)</sup>	Reverse leakage	$T_j = 25^\circ C$	V <sub>R</sub> = V <sub>RRM</sub>			50	
'R`	current	T <sub>j</sub> = 150° C	v <sub>R</sub> = v <sub>RRM</sub>		100	1000	μA
V <sub>E</sub> (2)	Forward voltage drop	$T_j = 25^\circ C$	I <sub>F</sub> = 60 A			1.2	v
VF.	Torward voltage drop	T <sub>j</sub> = 150° C	1F – 00 A		0.83	1.0	v
1. Pulse te	est: t <sub>p</sub> = 5 ms, δ < 2%			0	3		
2. Pulse te	est: t <sub>n</sub> = 380 μs. δ < 2%				<b>T</b>		

2. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses use the following equation:  $P = 0.8 \text{ x } I_{F(AV)} + 0.0033 I_{F^{2}(RMS)}^{2}$ 

	Symbol	Parameter	C	Test conditions	Min	Тур	Max	Unit
	t <sub>rr</sub>	Reverse recovery	T: - 25° C	$\begin{array}{l} I_F = 1 \ A  dI_F/dt = 50 \ A/\mu s \\ V_R = 30 \ V \end{array}$		66	90	ns
	۲r	time	1 - 23 0	$I_F = 1 A dI_F/dt = 200 A/\mu s$ $V_R = 30 V$		36	50	113
	I <sub>RM</sub>	Reverse recovery current	$T_j = 125^\circ C$	I <sub>F</sub> = 60 A V <sub>R</sub> = 200 V dI <sub>F</sub> /dt = 100 A/μs			15	A
	S <sub>factor</sub>	Softness factor	$T_{j} = 125^{\circ} C$	I <sub>F</sub> = 60 A V <sub>R</sub> = 200 V dI <sub>F</sub> /dt = 100 A/μs		0.4		
SOle	t <sub>fr</sub>			$I_{F} = 60 \text{ A} \qquad dI_{F}/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$			600	ns
005	V <sub>FP</sub>	Forward recovery voltage	$T_j = 25^\circ C$	$I_{F} = 60 \text{ A}  dI_{F}/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x} \text{ V}_{Fmax}$		3.2		V

#### Dynamic characteristics (per diode) Table 4.



15

10

5

0

0 50 100

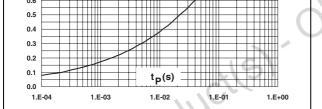


Figure 5. **Reverse recovery time versus** dl<sub>F</sub>/dt (typical values, per diode)

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Figure 6. **Reverse recovery charges versus** dl<sub>F</sub>/dt (typical values, per diode)

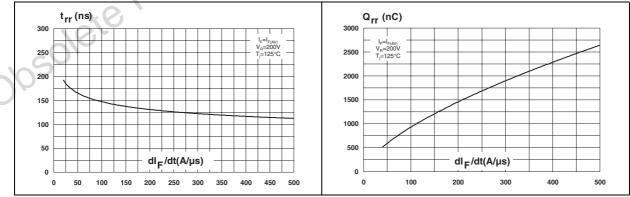
200 250

150

dl /dt(A/µs)

350 400 450 500

300



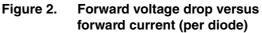


Figure 7. Reverse recovery softness factor versus dl<sub>F</sub>/dt (typical values, per diode)

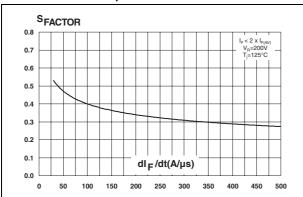
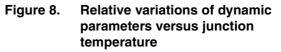


Figure 9. Transient peak forward voltage versus dl<sub>F</sub>/dt (typical values, per diode)



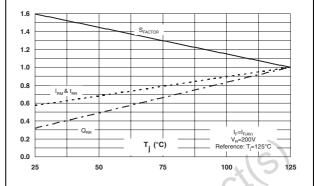


Figure 10. Forward recovery time versus dl<sub>F</sub>/dt (typical values, per diode)

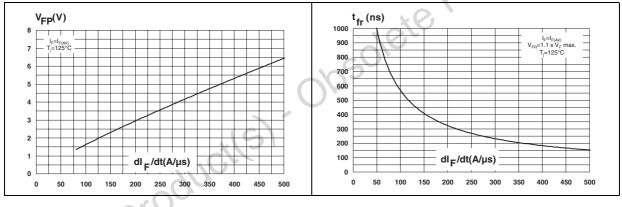
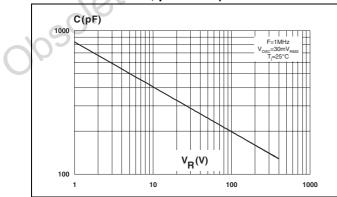


Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)

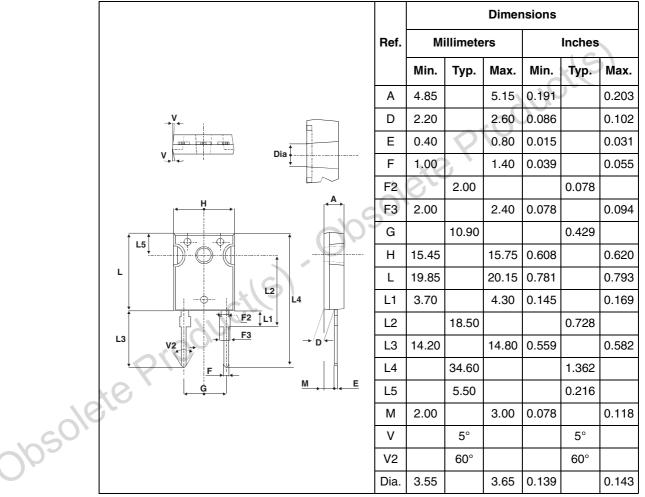




### 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 Nm
- Maximum torque value: 1.0 Nm

Table 5. DO-247 Dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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# **3** Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTH60L04W	STTH60L04W	DO-247	4.4 g	30	Tube

# 4 Revision history

Date	Revision	Description of Changes
26-Oct-2006	1	First issue
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